

# INK0602BC1

High Speed Switching  
Silicon N-channel MOSFET

## DESCRIPTION

INK0602BC1 is a Silicon N-channel MOSFET.

This product is most suitable for use such as portable machinery, because of low voltage drive and low on resistance.

## FEATURE

- Input impedance is high, and not necessary to consider a drive electric current.
- High drain current  $I_D=6.2A$
- Drive voltage 1.8V
- Low on Resistance.  $R_{DS(ON)}=18m\Omega$  typ(@ $V_{GS}=4.5V$ )  
 $R_{DS(ON)}=21m\Omega$  typ(@ $V_{GS}=2.5V$ ).  
 $R_{DS(ON)}=25m\Omega$  typ(@ $V_{GS}=1.8V$ )
- High speed switching.

## APPLICATION

High speed switching, Analog switching

## MAXIMUM RATINGS ( $T_a=25^\circ C$ )

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	$\pm 10$	V
Drain Current(DC)(※1)	$I_D$	6.2	A
Drain Current(Pulse) (※2)	$I_{DP}$	12	A
Total Power Dissipation (※1)	$P_D$	0.9	W
Channel Temperature	$T_{ch}$	+150	$^\circ C$
Storage Temperature	$T_{stg}$	-55~+150	$^\circ C$

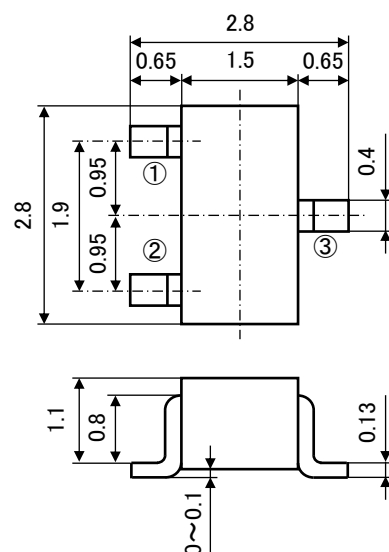
※1 package mounted on glass-epoxy substrate.

(39mm × 39mm × 1.6mm, Cu pad 1500mm<sup>2</sup>)

※2  $P_w \leq 10ms$ , Duty cycle  $\leq 1\%$

## OUTLINE DRAWING

Unit: mm



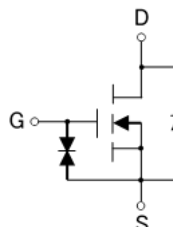
TERMINAL CONNECTOR

- ①: GATE
- ②: SOURCE
- ③: DRAIN

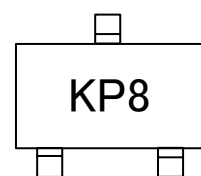
JEITA: SC-59

JEDEC: Similar to TO-236

## EQUIVALENT CIRCUIT



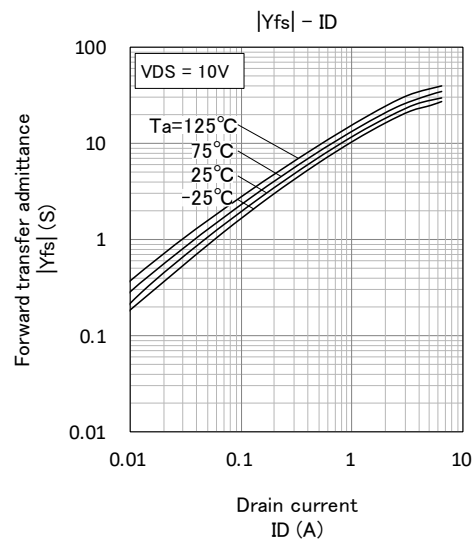
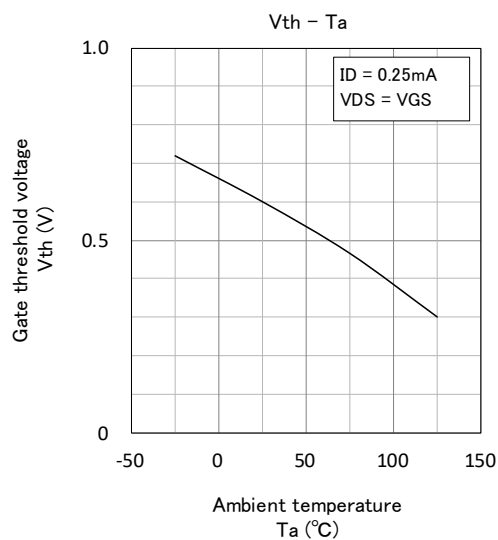
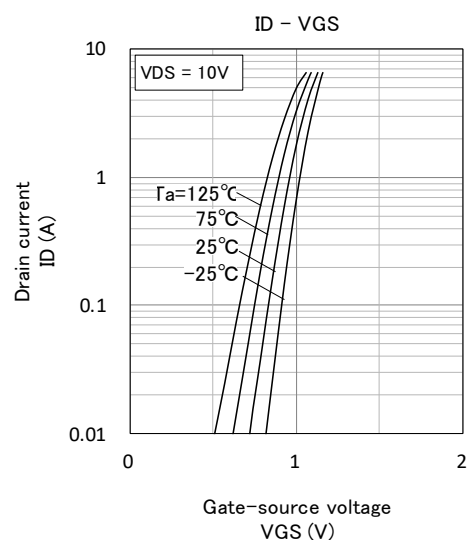
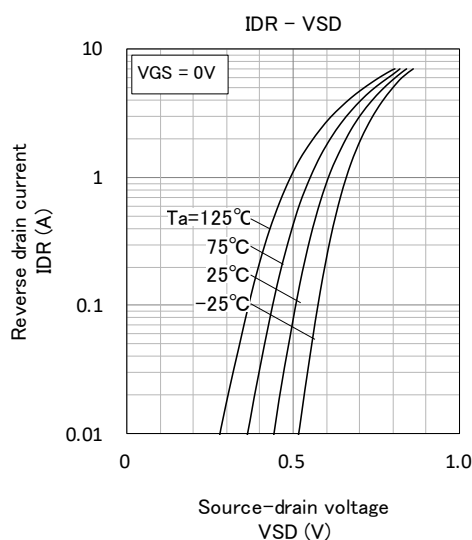
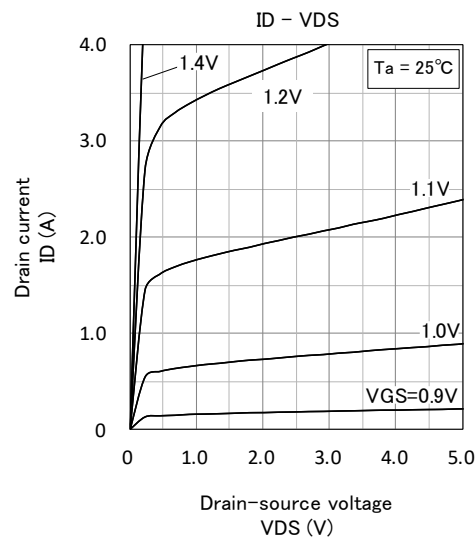
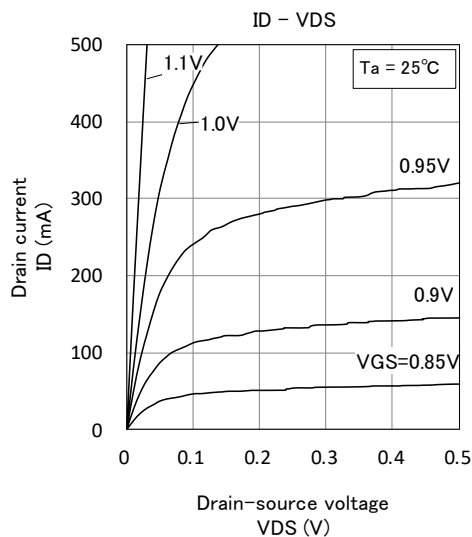
## MARKING



## ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ C$ )

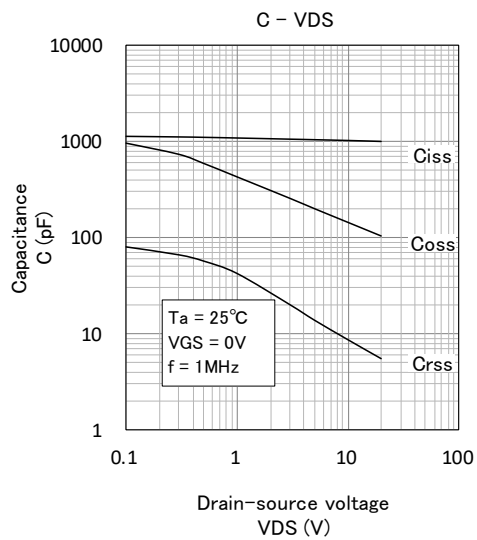
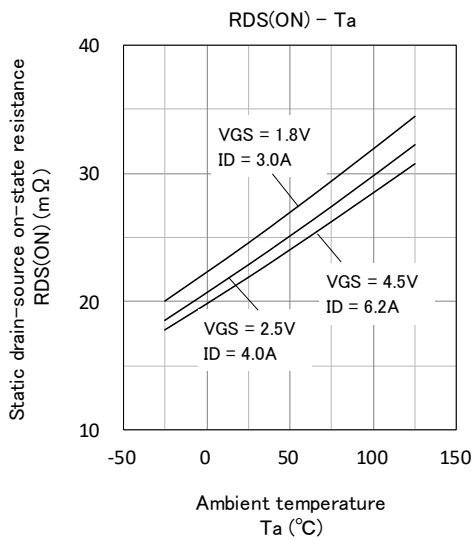
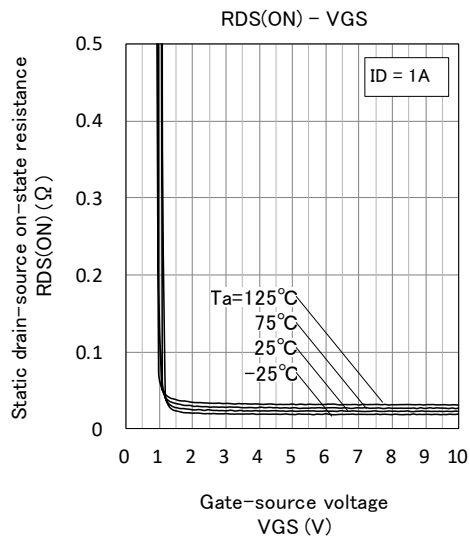
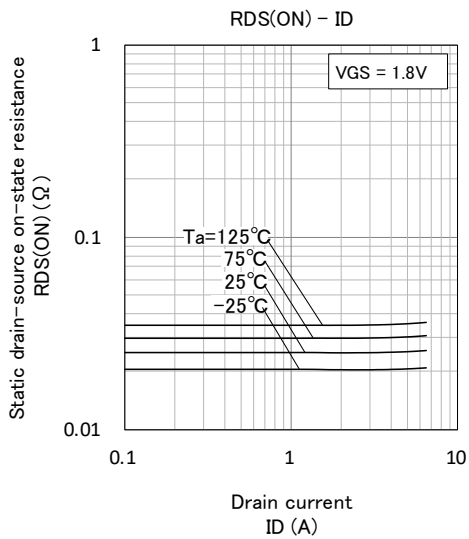
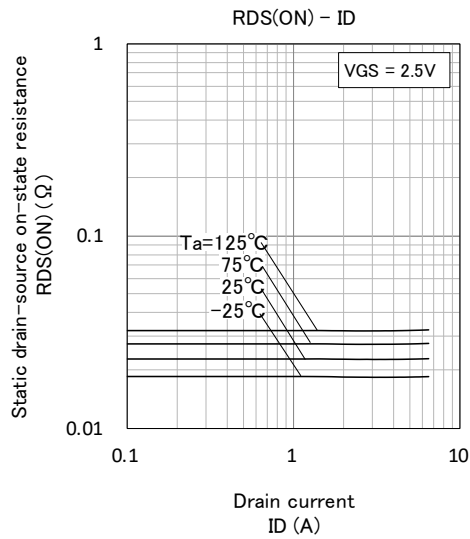
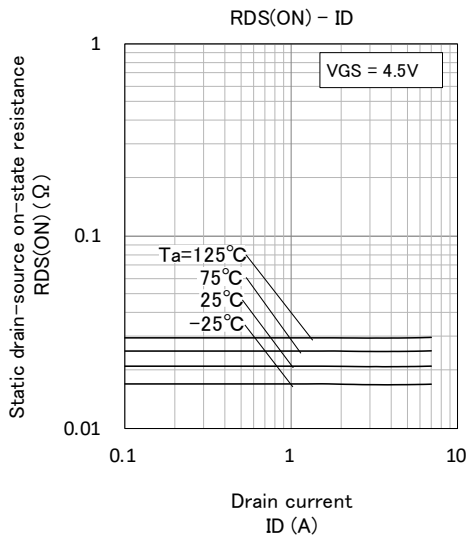
Parameter	Symbol	Test Condition	Limit			Unit
			MIN	TYP	MAX	
Drain-Source Breakdown Voltage	$V_{(BR)DS}$	$I_D=250\mu A$ , $V_{GS}=0V$	20	-	-	V
Gate-Source Leak Current	$I_{GSS}$	$V_{GS}=\pm 10V$ , $V_{DS}=0V$	-	-	$\pm 1.0$	$\mu A$
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=20V$ , $V_{GS}=0V$	-	-	1.0	$\mu A$
Gate Threshold Voltage	$V_{th}$	$I_D=250\mu A$ , $V_{DS}=V_{GS}$	0.3	-	1.0	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$I_D=6.2A$ , $V_{GS}=4.5V$	-	18	23	m $\Omega$
		$I_D=4.0A$ , $V_{GS}=2.5V$	-	21	29	
		$I_D=3.0A$ , $V_{GS}=1.8V$	-	25	31	
Input Capacitance	$C_{iss}$	$V_{DS}=10V$ , $V_{GS}=0V$ , $f=1MHz$	-	1050	-	pF
Output Capacitance	$C_{oss}$		-	145	-	
Feedback Capacitance	$C_{rss}$		-	10	-	
Switching Time	$t_{on}$	$V_{DD}=20V$ , $I_D=200mA$ , $V_{GS}=5V$	-	30	-	ns
	$t_{off}$		-	290	-	

## TYPICAL CHARACTERISTICS



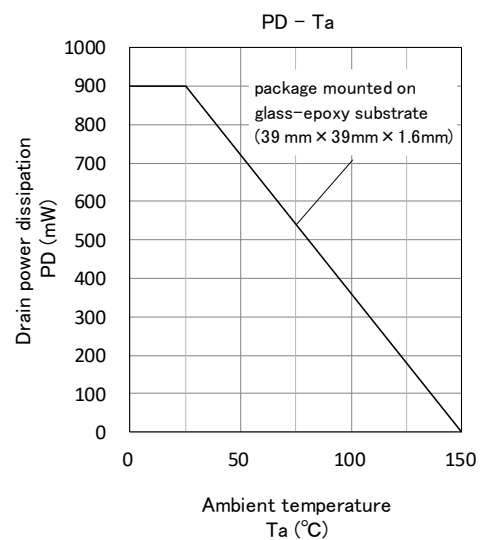
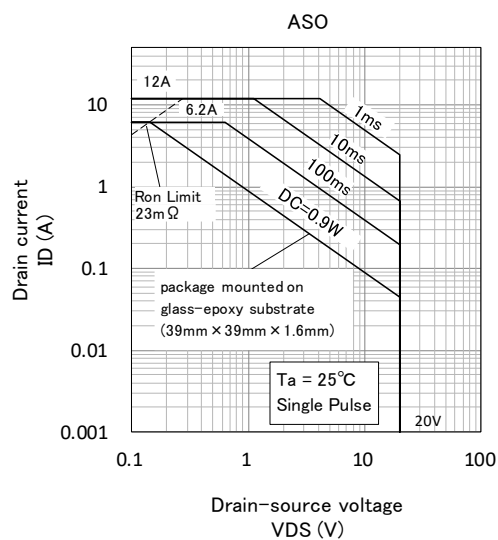
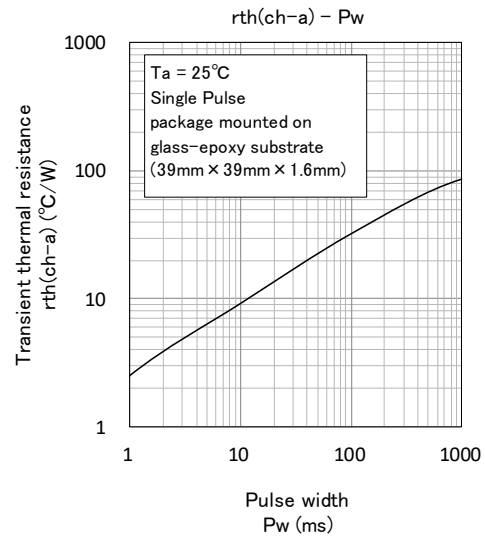
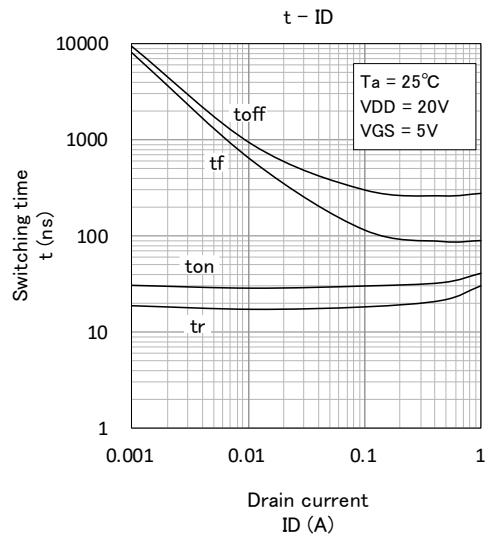
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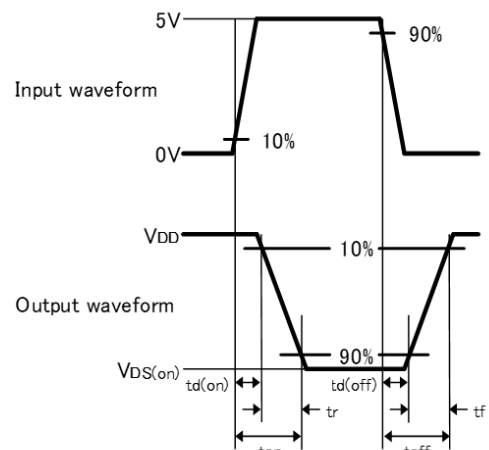
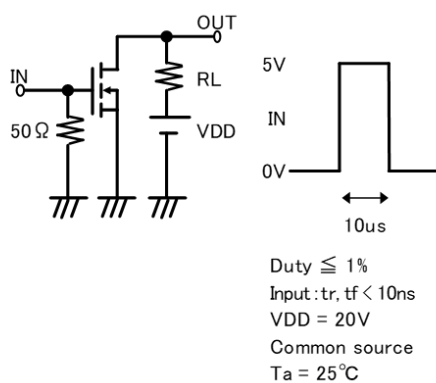


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## Switching time test condition



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